NSN 5962-01-195-2283

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View Online at https://aerobasegroup.com/nsn/5962-01-195-2283 **Body Length:** Between 1.190 inches and 1.290 inches **Body Width:** 0.610 inches **Body Height:** Between 0.090 inches and 0.170 inches **Maximum Power Dissipation Rating:** 0.83 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and bipolar and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 90.00 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a

Demilitarization:

Unit Of Measure:

Yes - demil/mli

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